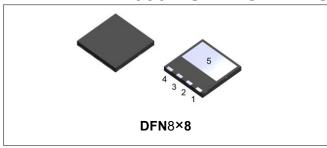






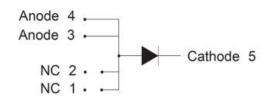
# S3D03065L 650V SIC POWER SCHOTTKY RECTIFIER



#### **Description**

S3D03065L is a SiC Schottky rectifier packaged in DFN8×8 case. The device is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D03065L is ideal for energy sensitive, high frequency applications in challenging environments.

### **Circuit Diagram**



# **Applications**

- · Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- · Switching supply output rectification
- Reverse polarity protection

### **Features**

- 175°C T<sub>J</sub> operation
- Ultra-low switching loss
- · Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

## **Maximum Ratings**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	-	650	٧
	I <sub>F (AV)1</sub>	Tc=25°C	17	Α
Average Rectified Forward Current	I <sub>F (AV)2</sub>	Tc=136°C	8	Α
	I <sub>F (AV)3</sub>	Tc=157°C	3	Α
	I <sub>FRM1</sub>	10ms, Half Sine pulse, Tc =25°C	23	Α
Repetitive Peak Forward Surge Current	I <sub>FRM2</sub>	10ms, Half Sine pulse, Tc=110°C	15	Α
	I <sub>FSM1</sub>	10ms, Half Sine pulse, Tc =25°C	46	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM2</sub>	10ms, Half Sine pulse, Tc =110°C	32	Α
Non-Repetitive Peak Forward Surge Current	I <sub>F,Max</sub>	10μs. Pulse, Tc=25°C	390	Α
Non-Nepetitive Feak Forward Surge Current	I <sub>F,Max</sub>	10µs. Pulse, Tc=110℃	265	Α
Davis Diagination	P <sub>tot1</sub>	Tc=25°C	60	W
Power Dissipation	P <sub>tot1</sub>	Tc=110°C	26	W

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 3A, Pulse, T <sub>J</sub> = 25 °C	1.4	1.7	V
	$V_{F2}$	@ 3A, Pulse, T <sub>J</sub> = 175 °C	1.6	2.0	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.03	2	uA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 175  ^{\circ}\text{C}$	0.3	20	uA
Junction Capacitance	Ст	V <sub>R</sub> =0V, T <sub>J</sub> =25℃, f=1MHz	230	-	pF
Reverse Recovery Charge	Qc	I <sub>F</sub> = 3A, di/dt = 200A/μs VR = 400 V, T <sub>J</sub> =25°C	14.35	-	nC
Capacitance Stored Energy	<b>E</b> c	V <sub>R</sub> = 400 V	3.51	-	μJ

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	2.5	°C/W

## **Marking Diagram**



Where XXXXX is YYWWL

S3D = Device Type
L = Package type
03 = Forward Current (3A)
065 = Reverse Voltage (650V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Ordering Information**

Device	Package	Shipping
S3D03065L	DFN 8×8	3000/Reel
S3D03065LTR	DFN 8×8	3000/Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

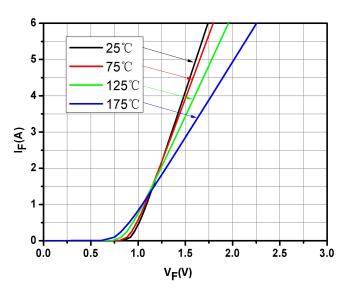
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### **Ratings and Characteristics Curves**

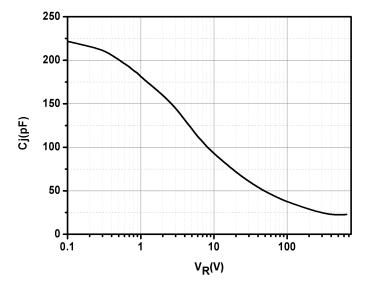


8 - 25°C -75°C -125°C -175°C -

10

Fig.1-Typical Forward Voltage Characteristics

**Fig.2-Typical Reverse Characteristics** 





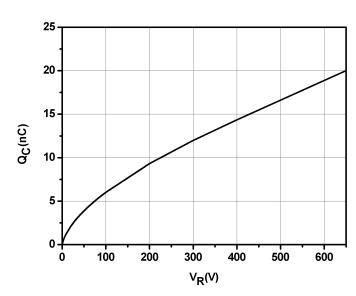
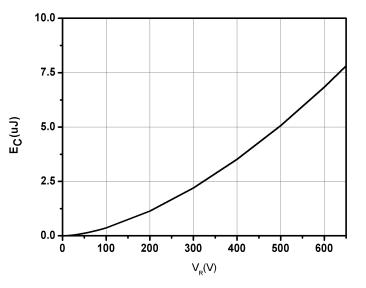


Fig.4-Total Capacitance Charge vs. Reverse Voltage









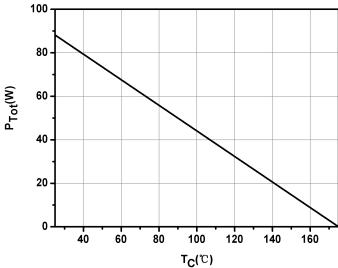


Fig.5-Capacitance Stored Energy

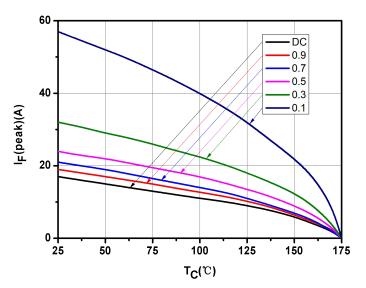


Fig.6-Power Derating

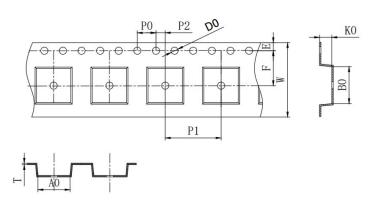
Fig.7-Current Derating





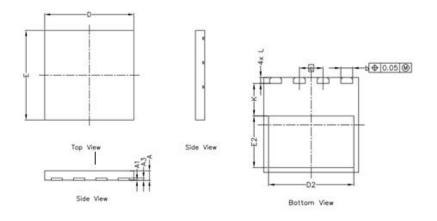


# Carrier Tape & Reel Specification DFN8×8



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
A0	8.30	8.50	
В0	8.40	8.60	
K0	1.20	1.40	
P0	3.90	4.10	
P1	11.90	12.10	
P2	1.95	2.05	
Т	0.20	0.30	
E	1.65	1.85	
F	7.40	7.60	
D0	1.50	1.60	
D1	1.50		
W	15.70	16.30	

### **Mechanical Dimensions DFN8×8**



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
Α	0.800	0.900	
A1	-	0.050	
A3	0.195	0.211	
D	7.900	8.100	
Е	7.900	8.100	
е	2.00 BSC		
р	0.950	1.050	
D2	7.100	7.300	
E2	4.250	4.450	
L	0.400	0.600	
K	2.650	2.850	







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